INTEGRATED CIRCUITS

DATA SHEET

For a complete data sheet, please also download:

- The IC04 LOCMOS HE4000B Logic Family Specifications HEF, HEC
- The IC04 LOCMOS HE4000B Logic Package Outlines/Information HEF, HEC

HEF4511B MSI BCD to 7-segment latch/decoder/driver

Product specification
File under Integrated Circuits, IC04

January 1995





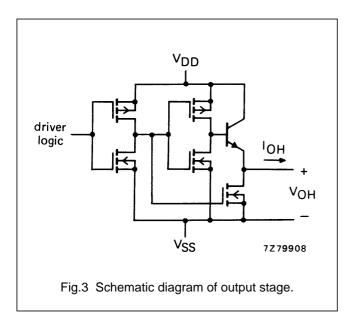
BCD to 7-segment latch/decoder/driver

HEF4511B MSI

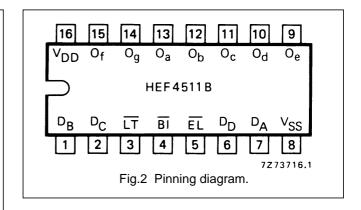
DESCRIPTION

The HEF4511B is a BCD to 7-segment latch/decoder/driver with four address inputs (D_A to D_D), an active LOW latch enable input (\overline{EL}), an active LOW ripple blanking input (\overline{BI}), an active LOW lamp test input (\overline{LT}), and seven active HIGH n-p-n bipolar transistor segment outputs (O_a to O_a).

6 D_B DC D_A D_D EL **LATCHES** ВΙ DECODER 3 LT **DRIVERS** Ob 0_a 12 | 13 10 7Z73717.2 Fig.1 Functional diagram.



When \overline{EL} is LOW, the state of the segment outputs (O_a to O_g) is determined by the data on D_A to D_D. When \overline{EL} goes HIGH, the last data present on D_A to D_D are stored in the latches and the segment outputs remain stable. When \overline{LT} is LOW, all the segment outputs are HIGH independent of all other input conditions. With \overline{LT} HIGH, a LOW on \overline{BI} forces all segment outputs LOW. The inputs \overline{LT} and \overline{BI} do not affect the latch circuit.



HEF4511BP(N): 16-lead DIL; plastic (SOT38-1)

HEF4511BD(F): 16-lead DIL; ceramic (cerdip) (SOT74)

HEF4511BT(D): 16-lead SO; plastic (SOT109-1)

(): Package Designator North America

PINNING

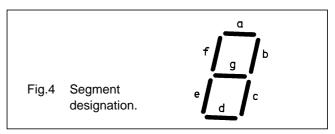
D_A to D_D address (data) inputs

 EL
 latch enable input (active LOW)

 BI
 ripple blanking input (active LOW)

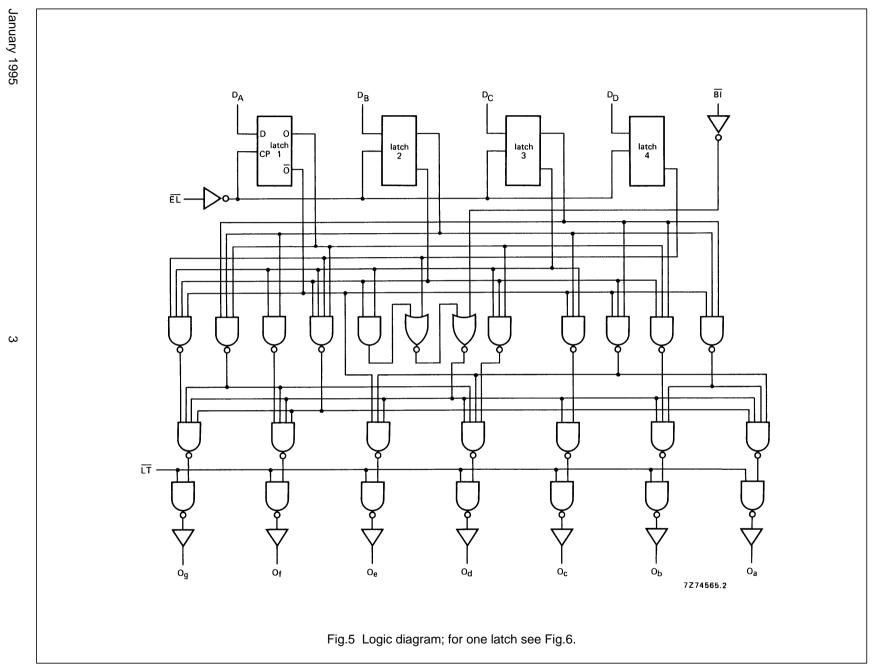
 LT
 lamp test input (active LOW)

O_a to O_g segment outputs



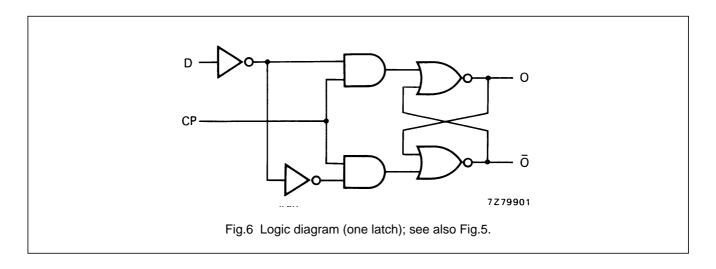
FAMILY DATA, IDD LIMITS category MSI

See Family Specifications



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FUNCTION TABLE

INPUTS								OUTPUTS						
EL	BI	LT	D _D	D _C	D _B	D _A	Oa	O _b	Oc	O _d	O _e	Of	Og	DISPLAY
Х	Х	L	Х	Χ	Χ	Χ	Н	Н	Н	Н	Н	Н	Н	8
Х	L	Н	Х	Χ	X	Χ	L	L	L	L	L	L	L	blank
L	Н	Н	L	L	L	L	Н	Н	Н	Н	Н	Н	L	0
L	Н	Н	L	L	L	Н	L	Н	Н	L	L	L	L	1 1
L	Н	Н	L	L	Н	L	н	Н	L	Н	Н	L	Н	2
L	Н	Н	L	L	Н	Н	н	Н	Н	Н	L	L	Н	3
L	Н	Н	L	Н	L	L	L	Н	Н	L	L	Н	Н	4
L	Н	Н	L	Н	L	Н	н	L	Н	Н	L	Н	Н	5
L	Н	Н	L	Н	Н	L	L	L	Н	Н	Н	Н	Н	6
L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	L	L	L	7
L	Н	Н	Н	L	L	L	Н	Н	Н	Н	Н	Н	Н	8
L	Н	Н	Н	L	L	Н	н	Н	Н	L	L	Н	Н	9
L	Н	Н	Н	L	Н	L	L	L	L	L	L	L	L	blank
L	Н	Н	Н	L	Н	Н	L	L	L	L	L	L	L	blank
L	Н	Н	Н	Н	L	L	L	L	L	L	L	L	L	blank
L	Н	Н	Н	Н	L	Н	L	L	L	L	L	L	L	blank
L	Н	Н	Н	Н	Н	L	L	L	L	L	L	L	L	blank
L	Н	Н	Н	Н	Н	Н	L	L	L	L	L	L	L	blank
Н	Н	Н	Х	Х	Х	Χ				*				*

Note

^{1.} H = HIGH state (the more positive voltage)

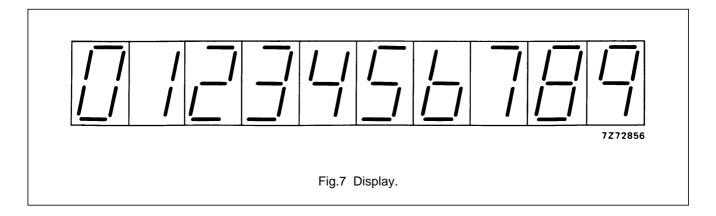
L = LOW state (the less positive voltage)

X = state is immaterial

^{*} Depends upon the BCD code applied during the LOW to HIGH transition of $\overline{\text{EL}}$.

BCD to 7-segment latch/decoder/driver

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RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134).

Output (source) current HIGH

 $-I_{OH}$ max. 25 mA

For other RATINGS see Family Specifications.

Note

1. A destructive high current mode may occur if V_I and V_O are not constrained to the range $V_{SS} \le V_I$ or $V_O \le V_{DD}$.

BCD to 7-segment latch/decoder/driver

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DC CHARACTERISTICS

 $V_{SS} = 0 V$

				T _{amb} (°C)							
HEF	V _{DD} V	I _{OH} mA	SYMBOL	-40		+ 25		+ 8	35		
				MIN.	MAX.	MIN.	TYP.	MIN.	MAX.		
Output voltage	5	0		4,10		4,10	4,40	4,10	V		
HIGH	10	0	V _{OH}	9,10		9,10	9,40	9,10	V		
	15	0		14,10		14,10	14,40	14,10	V		
Output voltage	5	5					4,20		V		
HIGH	10	5	V _{OH}				9,20		V		
	15	5					14,20		V		
Output voltage	5	10		3,60		3,60	4,05	3,30	V		
HIGH	10	10	V _{OH}	8,75		8,75	9,10	8,45	V		
	15	10		13,75		13,75	14,10	13,45	V		
Output voltage	5	15					4,00		V		
HIGH	10	15	V _{OH}				9,00		V		
	15	15					14,00		V		
Output voltage	5	20		2,80		2,80	3,80	2,50	V		
HIGH	10	20	V _{OH}	8,10		8,10	9,00	7,80	V		
	15	20		13,10		13,10	14,00	12,80	V		
Output voltage	5	25					3,70		V		
HIGH	10	25	V _{OH}				8,90		V		
	15	25					14,00		V		

BCD to 7-segment latch/decoder/driver

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				T _{amb} (°C)							
HEC	V _{DD}	I _{OH} mA	SYMBOL	–55		+ 25		+ 1	25		
		, \		MIN.	MAX.	MIN.	TYP.	MIN.	MAX.		
Output voltage	5	0		4,10		4,10	4,40	4,10	V		
HIGH	10	0	V _{OH}	9,10		9,10	9,90	9,10	V		
	15	0		14,10		14,10	14,40	14,40	V		
Output voltage	5	5					4,30		V		
HIGH	10	5	V _{OH}				9,30		V		
	15	5					14,30		V		
Output voltage	5	10		3,60		3,60	4,25	3,20	V		
HIGH	10	10	V _{OH}	8,75		8,75	9,25	8,35	V		
	15	10		13,75		13,75	14,25	13,35	V		
Output voltage	5	15					4,20		V		
HIGH	10	15	V _{OH}				9,20		V		
	15	15					14,20		V		
Output voltage	5	20		2,80		2,80	4,20	2,30	V		
HIGH	10	20	V _{OH}	8,10		8,10	9,20	7,60	V		
	15	20		13,10		13,10	14,20	12,60	V		
Output voltage	5	25					4,15		V		
HIGH	10	25	V _{OH}				9,20		V		
	15	25					14,20		V		

AC CHARACTERISTICS

 V_{SS} = 0 V; T_{amb} = 25 °C; input transition times \leq 20 ns

	V _{DD} V	TYPICAL FORMULA FOR P (μW)	
Dynamic power	5	1 000 $f_i + \sum (f_o C_L) \times V_{DD}^2$	where
dissipation per	10	4 000 $f_i + \sum (f_o C_L) \times V_{DD}^2$	$f_i = input freq. (MHz)$
package (P)	15	10 000 $f_i + \sum (f_o C_L) \times V_{DD}^2$	f _o = output freq. (MHz)
			C _L = load capacitance (pF)
			$\sum (f_0C_L) = \text{sum of outputs}$
			V _{DD} = supply voltage (V)

BCD to 7-segment latch/decoder/driver

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AC CHARACTERISTICS

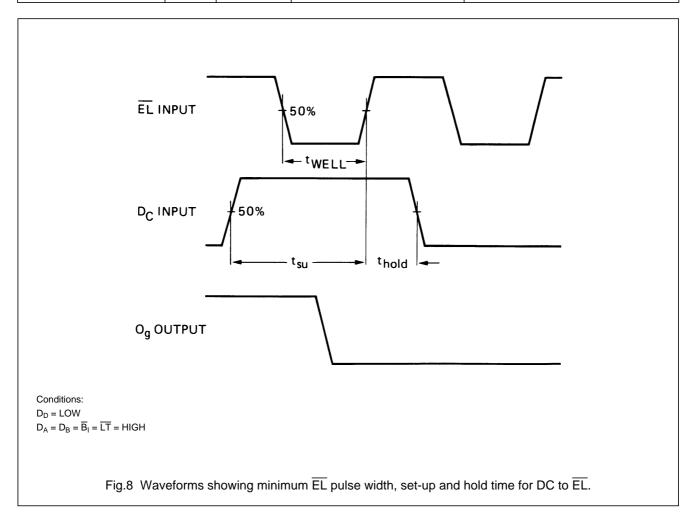
 V_{SS} = 0 V; T_{amb} = 25 °C; C_L = 50 pF; input transition times \leq 20 ns

	V _{DD}	SYMBOL	MIN.	TYP.	MAX.		TYPICAL EXTRAPOLATION FORMULA
Propagation delays							
$D_n \rightarrow O_n$	5			155	310	ns	128 ns + (0,55 ns/pF) C _L
HIGH to LOW	10	t _{PHL}		60	120	ns	49 ns + (0,23 ns/pF) C _L
	15			40	80	ns	32 ns + (0,16 ns/pF) C _L
	5			135	270	ns	108 ns + (0,55 ns/pF) C _L
LOW to HIGH	10	t _{PLH}		55	110	ns	44 ns + (0,23 ns/pF) C _L
	15			40	80	ns	32 ns + (0,16 ns/pF) C _L
$\overline{EL} o O_n$	5			160	320	ns	133 ns + (0,55 ns/pF) C _L
HIGH to LOW	10	t _{PHL}		60	120	ns	49 ns + (0,23 ns/pF) C _L
	15			45	90	ns	37 ns + (0,16 ns/pF) C _L
	5			160	320	ns	133 ns + (0,55 ns/pF) C _L
LOW to HIGH	10	t _{PLH}		70	140	ns	59 ns + (0,23 ns/pF) C _L
	15			50	100	ns	42 ns + (0,16 ns/pF) C _L
$\overline{BI} \to O_n$	5			120	240	ns	93 ns + (0,55 ns/pF) C _L
HIGH to LOW	10	t _{PHL}		50	100	ns	39 ns + (0,23 ns/pF) C _L
	15			35	70	ns	27 ns + (0,16 ns/pF) C _L
$\overline{BI} \to O_n$	5			105	210	ns	78 ns + (0,55 ns/pF) C _L
LOW to HIGH	10	t _{PLH}		40	80	ns	29 ns + (0,23 ns/pF) C _L
	15			30	60	ns	22 ns + (0,16 ns/pF) C _L
$\overline{LT} \rightarrow O_n$	5			80	160	ns	52 ns + (0,55 ns/pF) C _L
HIGH to LOW	10	t _{PHL}		30	60	ns	19 ns + (0,23 ns/pF) C _L
	15			20	40	ns	12 ns + (0,16 ns/pF) C _L
	5			60	120	ns	33 ns + (0,55 ns/pF) C _L
LOW to HIGH	10	t _{PLH}		30	60	ns	19 ns + (0,23 ns/pF) C _L
	15			25	50	ns	17 ns + (0,16 ns/pF) C _L
Output transition times	5			60	120	ns	10 ns + (1,0 ns/pF) C _L
HIGH to LOW	10	t _{THL}		30	60	ns	9 ns + (0,42 ns/pF) C _L
	15			20	40	ns	6 ns + (0,28 ns/pF) C _L
	5			25	50	ns	20 ns + (1,0 na/pF) C _L
LOW to HIGH	10	t _{TLH}		16	32	ns	13 ns + (0,06 ns/pF) C _L
	15			13	26	ns	10 ns + (0,06 ns/pF) C _L

BCD to 7-segment latch/decoder/driver

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	V _{DD}	SYMBOL	MIN.	TYP.	MAX.	TYPICAL EXTRAPOLATION FORMULA
Minimum EL	5		80	40	ns	
pulse width; LOW	10	t _{WELL}	40	20	ns	
	15		35	17	ns	
Set-up time	5		50	25	ns	
$D_n \rightarrow \overline{EL}$	10	t _{su}	25	12	ns	see also waveforms Fig.8
	15		20	9	ns	1 19.0
Hold-time	5		60	30	ns	
$D_n \rightarrow \overline{EL}$	10	t _{hold}	30	15	ns	
	15		25	12	ns	



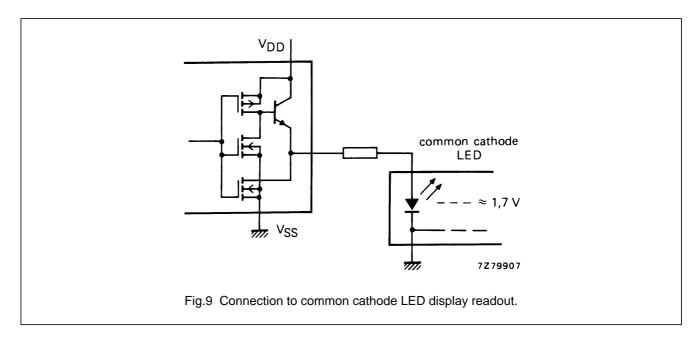
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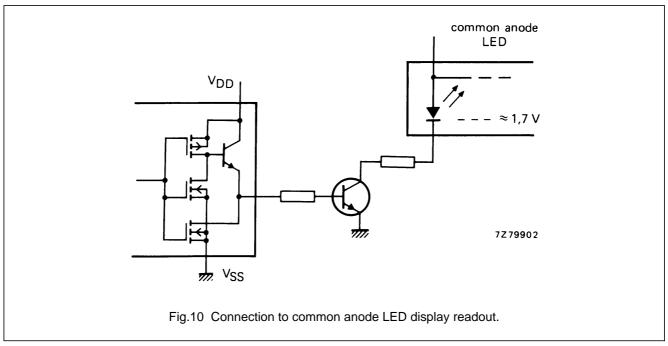
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APPLICATION INFORMATION

Some examples of applications for the HEF4511B are:

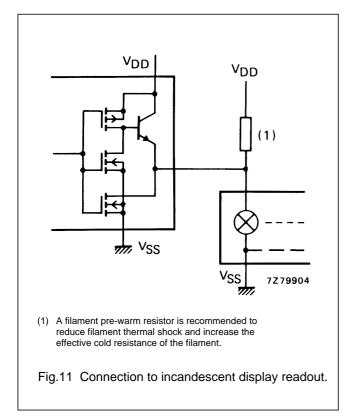
- Driving LED displays.
- Driving incandescent displays.
- Driving fluorescent displays.
- Driving LCD displays.
- Driving gas discharge displays.

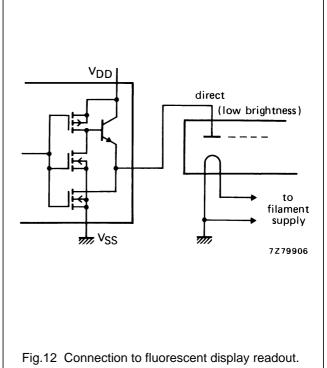


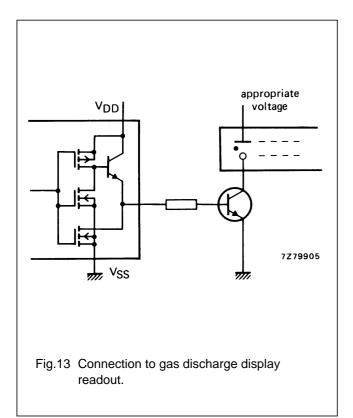


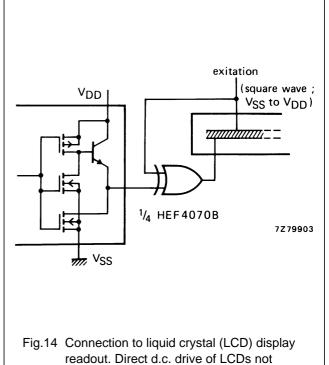
BCD to 7-segment latch/decoder/driver

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recommended for life of LCD readouts.

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